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October 2013

FDP070AN06A0

N-Channel PowerTrench[®] MOSFET 60 V, 80 A, 7 m Ω

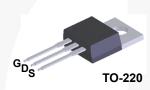
Features

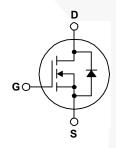
- $R_{DS(on)}$ = 6.1 m Ω (Typ.) @ V_{GS} = 10 V, I_D = 80 A
- $Q_{g(tot)} = 51 \text{ nC (Typ.)} @ V_{GS} = 10 \text{ V}$
- · Low Miller Charge
- · Low Q_{rr} Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)

Formerly developmental type 82567

Applications

- Synchronous Rectification for ATX / Server / Telecom PSU
- Battery Protection Circuit
- Motor Drives and Uninterruptible Power Supplies





MOSFET Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter	FDP070AN06A0	Unit
V _{DSS}	Drain to Source Voltage	60	V
V _{GS}	Gate to Source Voltage	±20	V
	Drain Current		
I_D	Continuous (T _C < 97°C, V _{GS} = 10V)	80	Α
	Pulsed	Figure 4	Α
E _{AS}	Single Pulse Avalanche Energy (Note 1)	190	mJ
	Power dissipation	175	W
P_{D}	Derate above 25°C	1.17	W/°C
T _J , T _{STG}	Operating and Storage Temperature	-55 to 175	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance Junction to Case, Max.	0.86	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient, Max. (Note 2)	62	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP070AN06A0	FDP070AN06A0	TO-220	N/A	N/A	50 units

Electrical Characteristics $T_C = 25$ °C unless otherwise noted.

Symbol	Parameter	Test Conditions		Min	Тур	Max	Unit
Off Chara	cteristics						
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS}	= 0V	60	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 50V		-	-	1	μА
		$V_{GS} = 0V$	$T_{\rm C} = 150^{\rm o}{\rm C}$	-	-	250	
I _{GSS}	Gate to Source Leakage Current	V _{GS} = ±20V		-	-	±100	nA
On Chara	cteristics						
V _{GS(TH)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D =$	250μΑ	2	-	4	V
,		I _D = 80A, V _{GS} =			0.0061	0.007	
r _{DS(ON)}	Drain to Source On Resistance	$I_D = 80A, V_{GS} = T_J = 175^{\circ}C$	10V,	-	0.0127	0.015	Ω
Dynamic	Characteristics				•		
C _{ISS}	Input Capacitance			-	3000	_	pF
C _{OSS}	Output Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$		- \	510	-	pF
C _{RSS}	Reverse Transfer Capacitance	f = 1MHz		-	230	-	pF
$Q_{g(TOT)}$	Total Gate Charge at 10V	V _{GS} = 0V to 10V	'		51	66	nC
$Q_{g(TH)}$	Threshold Gate Charge	V _{GS} = 0V to 2V	V _{DD} = 30V	-	5.4	7	nC
Q _{gs}	Gate to Source Gate Charge		I _D = 80A	-	17	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau		$I_g = 1.0 \text{mA}$	-	11.6	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			-	16	-	nC
Switching	Characteristics (V _{GS} = 10V)						
t _{ON}	Turn-On Time			- /	-	256	ns
t _{d(ON)}	Turn-On Delay Time			-/	12	-	ns
t _r	Rise Time	$V_{DD} = 30V, I_{D} =$	80A	-	159	-	ns
t _{d(OFF)}	Turn-Off Delay Time	$V_{GS} = 10V, R_{GS} = 5.6\Omega$		-	27	-	ns
t _f	Fall Time			-	35	-	ns
t _{OFF}	Turn-Off Time			-	-	93	ns
 Drain-Sou	urce Diode Characteristics						
		I _{SD} = 80A		-	-	1.25	V
V_{SD}	Source to Drain Diode Voltage	I _{SD} = 40A		-	-	1.0	V
t _{rr}	Reverse Recovery Time	I_{SD} = 75A, dI_{SD}/dI_{SD}	dt = 100A/μs	-	-	34	ns
Q _{RR}	Reverse Recovered Charge	I _{SD} = 75A, dI _{SD} /dt = 100A/μs		-	-	35	nC

Notes: 1: Starting T_J = 25°C, L = 93 μ H, I_{AS} = 64A. 2: Pulse width = 100s.

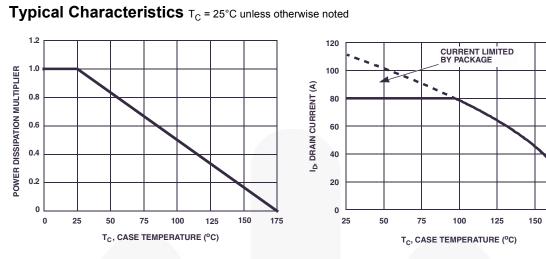


Figure 1. Normalized Power Dissipation vs Ambient Temperature

Figure 2. Maximum Continuous Drain Current vs Case Temperature

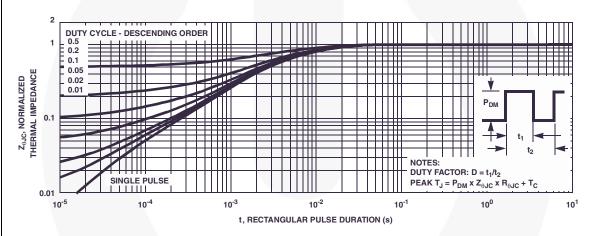


Figure 3. Normalized Maximum Transient Thermal Impedance

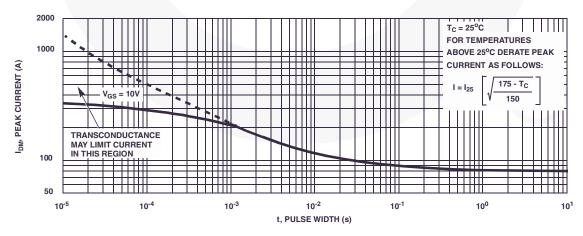
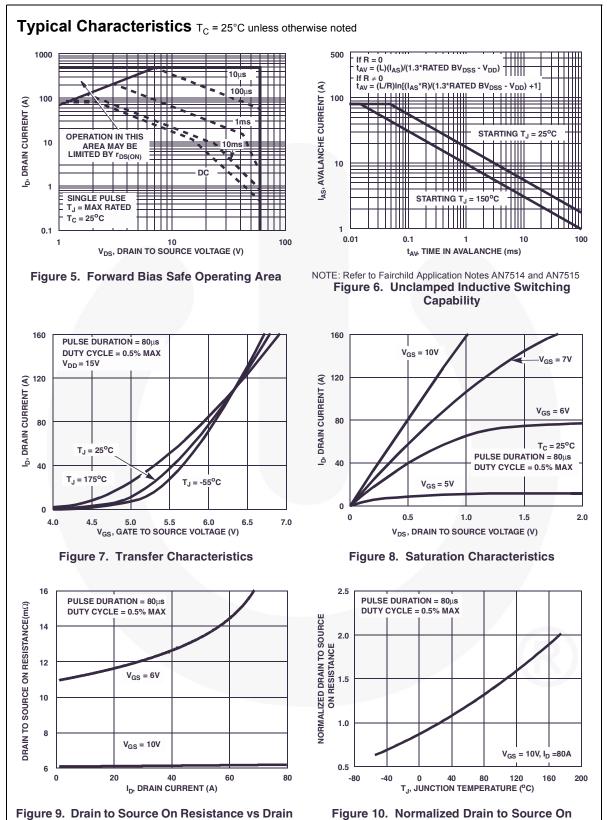


Figure 4. Peak Current Capability



Current

Resistance vs Junction Temperature

Typical Characteristics T_C = 25°C unless otherwise noted

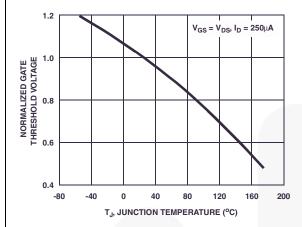


Figure 11. Normalized Gate Threshold Voltage vs Junction Temperature

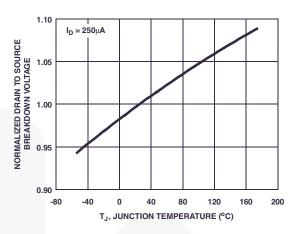


Figure 12. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

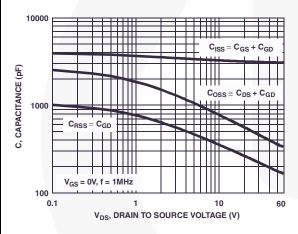


Figure 13. Capacitance vs Drain to Source Voltage

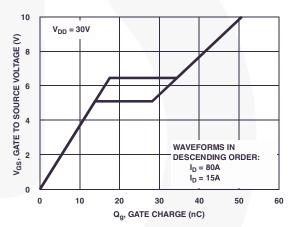


Figure 14. Gate Charge Waveforms for Constant Gate Current

Test Circuits and Waveforms

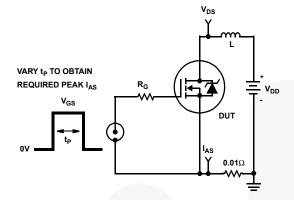


Figure 15. Unclamped Energy Test Circuit

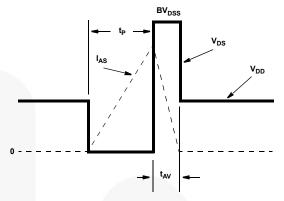


Figure 16. Unclamped Energy Waveforms

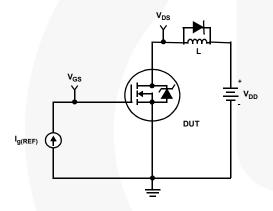


Figure 17. Gate Charge Test Circuit

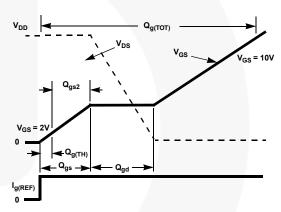


Figure 18. Gate Charge Waveforms

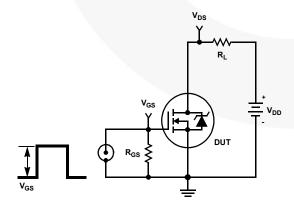


Figure 19. Switching Time Test Circuit

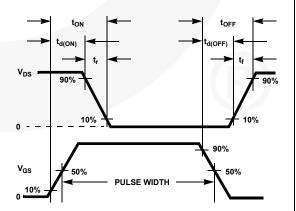
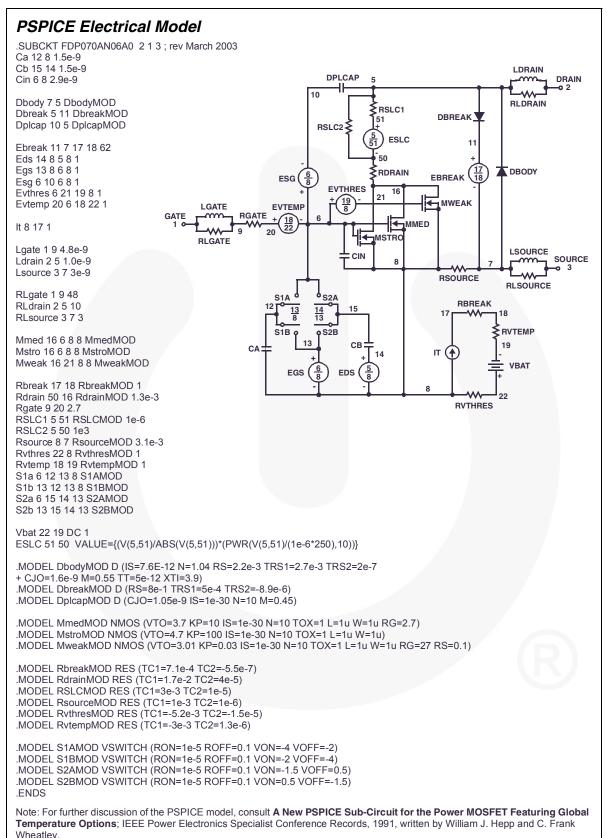
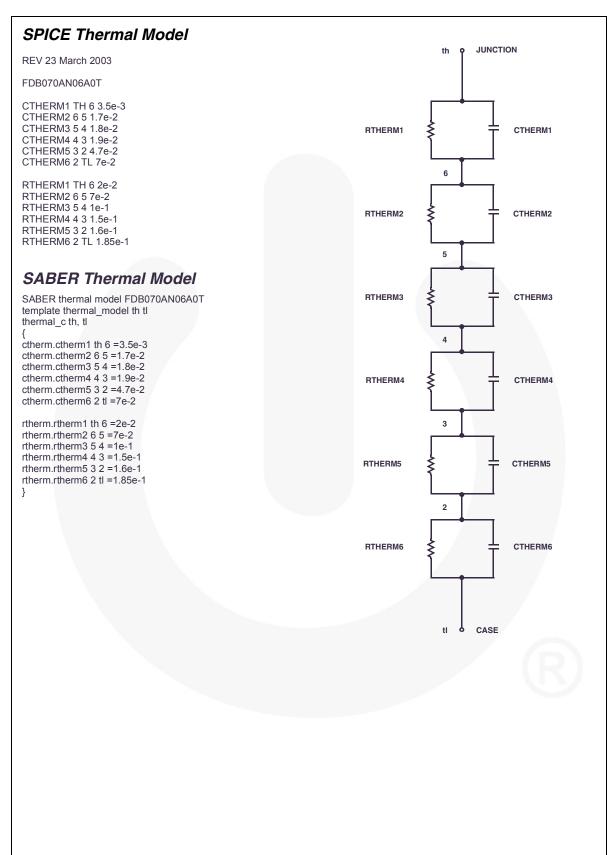


Figure 20. Switching Time Waveforms



SABER Electrical Model rev March 2003 template FDP070AN06A0 n2,n1,n3 electrical n2,n1,n3 var i iscl dp..model dbodymod = (isl=7.6e-12,nl=1.04,rs=2.2e-3,trs1=2.7e-3,trs2=2e-7,cjo=1.6e-9,m=0.55,tt=5e-12,xti=3.9) dp..model dbreakmod = (rs=8e-1,trs1=5e-4,trs2=-8.9e-6) dp..model dplcapmod = (cjo=1.05e-9,isl=10e-30,nl=10,m=0.45) m..model mmedmod = (type=_n,vto=3.7,kp=10,is=1e-30, tox=1) m..model mstrongmod = (type=_n,vto=4.7,kp=100,is=1e-30, tox=1) m..model mweakmod = $(type=_n, vto=3.01, kp=0.03, is=1e-30, tox=1, rs=0.1)$ LDRAIN sw vcsp..model s1amod = (ron=1e-5,roff=0.1,von=-4,voff=-2) **DPLCAP** DRAIN sw_vcsp..model s1bmod = (ron=1e-5,roff=0.1,von=-2,voff=-4) 10 sw_vcsp..model s2amod = (ron=1e-5,roff=0.1,von=-1.5,voff=0.5) RLDRAIN sw_vcsp..model s2bmod = (ron=1e-5,roff=0.1,von=0.5,voff=-1.5) RSLC1 c.ca n12 n8 = 1.5e-9RSLC₂ c.cb n15 n14 = 1.5e-9 ISCL c.cin n6 n8 = 2.9e-9DBREAK 50 dp.dbody n7 n5 = model=dbodymod RDRAIN dp.dbreak n5 n11 = model=dbreakmod 8 ESG (dp.dplcap n10 n5 = model=dplcapmod ■ DBODY **EVTHRES** 21 MWFAK spe.ebreak n11 n7 n17 n18 = 62 LGATE EVTEME **RGATE** MMED spe.eds n14 n8 n5 n8 = 1 **EBREA** 9 20 spe.egs n13 n8 n6 n8 = 1 MSTRO RLGATE spe.esq n6 n10 n6 n8 = 1 **LSOURCE** spe.evthres n6 n21 n19 n8 = 1 CIN SOURCE spe.evtemp n20 n6 n18 n22 = 1 **RSOURCE** RLSOURCE i.it n8 n17 = 1RBREAK I.lgate n1 n9 = 4.8e-917 18 I.ldrain n2 n5 = 1.0e-9 **₹**RVTEMP I.Isource n3 n7 = 3e-9 СВ 19 CA ΙT res.rlgate n1 n9 = 48 VBAT res.rldrain n2 n5 = 10 **EGS** res.rlsource n3 n7 = 3 m.mmed n16 n6 n8 n8 = model=mmedmod, l=1u, w=1u **RVTHRES** m.mstrong n16 n6 n8 n8 = model=mstrongmod, l=1u, w=1u m.mweak n16 n21 n8 n8 = model=mweakmod, l=1u, w=1u res.rbreak n17 n18 = 1, tc1=7.1e-4,tc2=-5.5e-7 res.rdrain n50 n16 = 1.3e-3, tc1=1.7e-2,tc2=4e-5 res.rgate n9 n20 = 2.7res.rslc1 n5 n51 = 1e-6, tc1=3e-3,tc2=1e-5 res.rslc2 n5 n50 = 1e3 res.rsource n8 n7 = 3.1e-3, tc1=1e-3,tc2=1e-6 res.rvthres n22 n8 = 1, tc1=-5.2e-3,tc2=-1.5e-5 res.rvtemp n18 n19 = 1, tc1=-3e-3,tc2=1.3e-6 sw vcsp.s1a n6 n12 n13 n8 = model=s1amod sw_vcsp.s1b n13 n12 n13 n8 = model=s1bmod sw_vcsp.s2a n6 n15 n14 n13 = model=s2amod sw vcsp.s2b n13 n15 n14 n13 = model=s2bmod v.vbat n22 n19 = dc=1 equations { i (n51->n50) +=iscl iscl: v(n51,n50) = ((v(n5,n51)/(1e-9+abs(v(n5,n51))))*((abs(v(n5,n51)*1e6/250))** 10))



Mechanical Dimensions

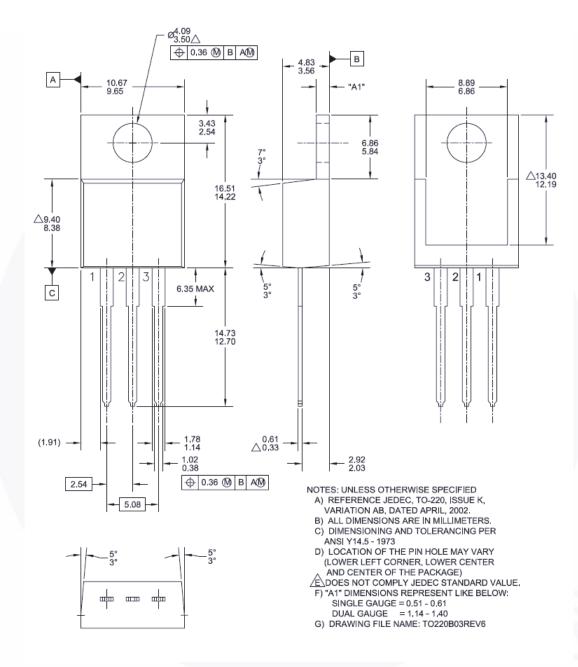


Figure 21. TO-220, Molded, 3-Lead, Jedec Variation AB

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